

KSC388

TV Final Picture IF Amplifier Applications

- G_{PE}= 33dB (TYP) at f=45MHz
 Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



1. Emitter 2. Base 3. Collector WWW.DZSC.CO

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	25	V
V _{EBO}	Emitter-Base Voltage	4	V
Ic	Collector Current	50	mA
P _C	Collector Power Dissipation	300	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

BV _{CBO}	Parameter	Test Condition	Min.	Тур.	Max.	Units
	Collector-Base Breakdown Voltage	$I_{C}=10\mu A, I_{E}=0$	30			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =5mA, I _B =0	25			V
I _{CBO}	Collector Cut-off Current	V_{CB} =30V, I_E =0			0.1	μΑ
I _{EBO}	Emitter Cut-off Current	V_{EB} =3V, I_{C} =0			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =12.5V, I _C =12.5mA	20		200	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =15mA, I _B =1.5mA			0.2	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =15mA, I _B =1.5mA			1.5	V
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz	0.8		2	pF
C _{c·rbb′}	Collector-Base Time Constant	V _{CB} =10V, I _C =1mA f=30MHz	Mile	WW	25	ps
f _T	Current Gain Bandwidth Product	V _{CE} =12.5V, I _C =12.5mA	300			MHz
G _{PE}	Power Gain	V _{CC} =12.5V, I _C =12.5mA f=45MHz	28	33	36	dB

Typical Characteristics

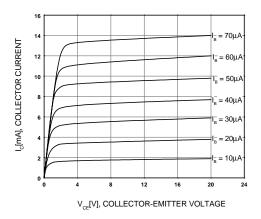


Figure 1. Static Characteristic

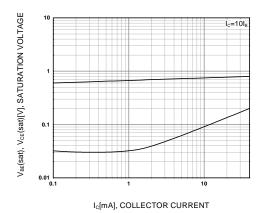


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

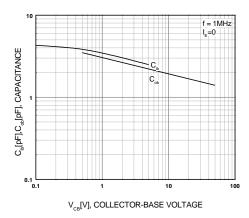


Figure 5. Collector Input Capacitance Collector Output Capacitance

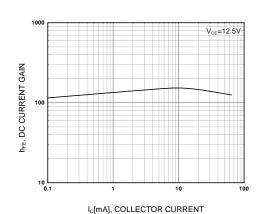


Figure 2. DC current Gain

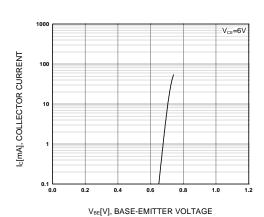


Figure 4. Base-Emitter On Voltage

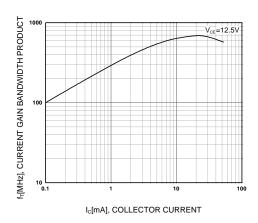
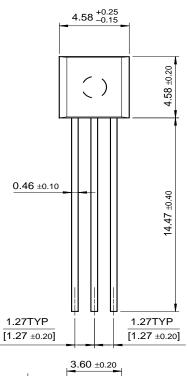


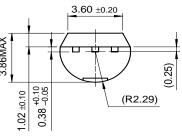
Figure 6. Current Gain Bandwidth Product

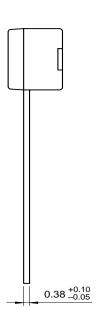
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Package Dimensions

TO-92







Dimensions in Millimeters

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CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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